

#### CS3120



#### Introduction of Integrated Circuit Design



# Homework 2: Layout Design

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- **♦** Description
- ◆Input/Output
- **♦**Report
- **◆**Grading
- **◆**DRC Rules
- **♦** Notice







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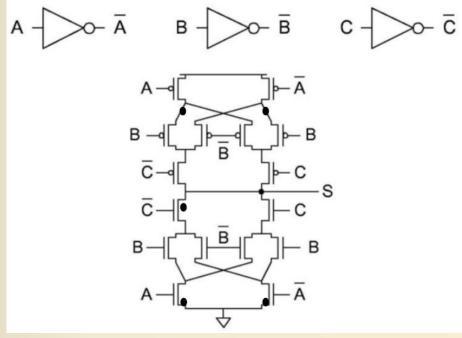






### Description

- Design a 3-input XOR gate which drives a capacitance of 0.005pF
- ◆ Use the design form in the document









### Description

- ◆Operating voltage (VDD): 1.8V
- ◆Operating temperature: 30°C
- ◆ Capacitive of output S is 0.005pF
- **♦** For transistors
  - > set L = 0.18um
  - The minimum value of W is 0.25um, and the value of W can be adjusted as needed







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- ◆The input should include the combinations of (A, B, C) = (0, 0, 0), (0, 0, 1), (0, 1, 0), (0, 1, 1), (1, 0, 0), (1, 0, 1), (1, 1, 0) and (1, 1, 1) in sequence
- The naming and pinouts of each input and output must match the figures provided in the document







- **◆Input signals:** 
  - ≥50% duty cycle
  - A operates at 200 MHz, B at 100 MHz, and C at 50 MHz
  - The order of input combinations (A, B, C) should match the orders in the document
  - >Set rise/fall time of the input signals to 10ps







- **♦**Output signals:
  - ➤ Highest voltage must be larger than 0.9VDD
  - Lowest voltage must be lower than 0.1VDD







- ◆ Need to show the delay and the difference in delay between rising and falling delay in the 3input XOR gate
  - ➤ Delay1\_XOR: signal A and S are falling
  - ➤ Delay2\_XOR: signal A and S are rising
  - Delay1\_XOR-Delay2\_XOR | = \_\_\_\_\_ ps







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### Report

- The circuit diagram of your design and explaining your design
- 2. Pre-sim waveform
- 3. Screenshot of your layout
- 4. Screenshot of DRC summary report
- Screenshot of LVS report include the message of passing LVS







### Report

- 6. Post-sim waveform
- 7. Screenshot of the post-simulation result
- 8. Write down your delay and the difference in delay between rising and falling delay in the 3-input XOR gate
- The hardness of this assignment and how you overcome it
- 10. Any suggestions about this programming assignment





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### Grading

◆Correctness: 40%

> Pre-sim: 10%

➤ DRC: 10%

> LVS: 10%

Post-sim: 10%

◆ Performance: power, area 10%

◆ Readability of hspice code: 10%

◆Report: 10%

◆ Demo session: 30%

**♦** Bonus: 10%







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### **DRC Rules**

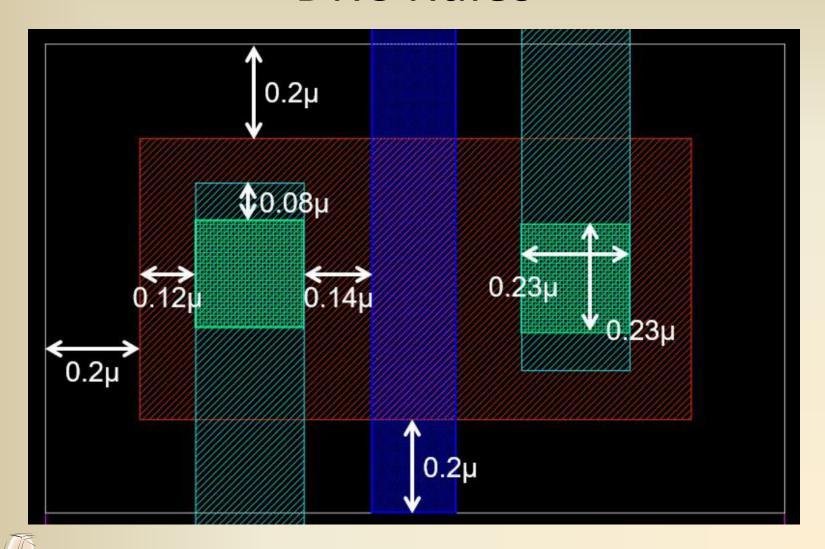
- ◆cont width and length = 0.23µm
- ◆Spacing between cont and diff > 0.12µm
- ◆Spacing between Pimp/Nimp and diff > 0.2μm
- ◆Spacing between poly and cont > 0.14µm
- ◆Spacing between metal and metal > 0.24µm
- ◆Spacing between cont and cont > 0.25μm







### **DRC** Rules







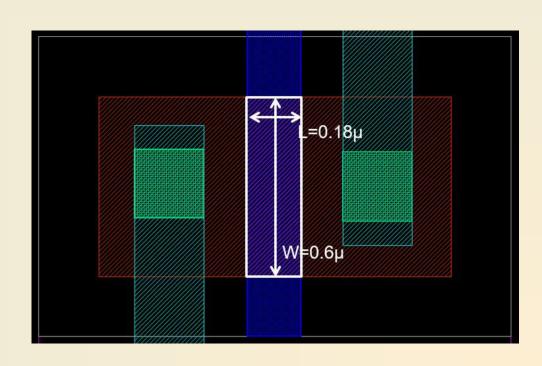
### **DRC Rules**

◆The length of W is determined by your design

➤ Will compare with the HSPICE code when you run

LVS

◆The W and L in your layout must be the same as the ones in HSPICE code









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### **Notice**

- ◆Only Metal 1 \ Metal 2 and Via can be used when routing
- ◆You must use the same approach as 'cic018.l' and 'cic18.tf' in HW2 to do this assignment; otherwise, you will get 0 points
- ◆BE SURE to follow the naming rule in the document; otherwise, your program will not be graded

